# OSRAM SFH 213 Datasheet

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Radial T1 3/4

Silicon PIN Photodiode





#### Applications

- Access Control & Security

- Appliances & Tools

#### **Features**

- Package: clear epoxy
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- Wavelength range ( $S_{10\%}$ ) 400 nm to 1100 nm
- Short switching time (typ. 5 ns)
- 5 mm LED plastic package

#### SFH 213 DATASHEET



### **Ordering Information**

Type Photocurrent <sup>1)</sup>		Photocurrent typ.	Ordering Code
	$E_v = 1000 \text{ lx}; \text{ Std. Light A; } V_R = 5 \text{ V}$	51	
SFH 213	≥ 110 µA	135 µA	Q62702P0930



## Maximum Ratings $T = 25 \degree C$

T <sub>A</sub> = 25 °C			
Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min.	-40 °C
	őþ	max.	100 °C
Storage temperature	T <sub>stg</sub>	min.	-40 °C
	otg	max.	100 °C
Reverse voltage	V <sub>R</sub>	max.	20 V
Reverse voltage	V <sub>R</sub>	max.	50 V
t ≤ 2 min; T <sub>A</sub> = 25 °C			
Total power dissipation	P <sub>tot</sub>	max.	150 mW
ESD withstand voltage	V <sub>ESD</sub>	max.	2 kV
acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	200		



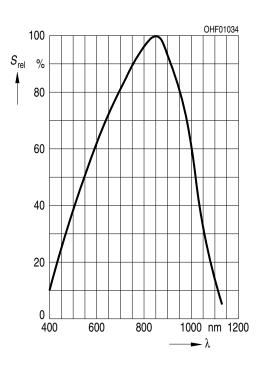
#### **Characteristics**

T <sub>A</sub> = 25 °C			
Parameter	Symbol		Values
Wavelength of max sensitivity	$\lambda_{_{Smax}}$	typ.	850 nm
Spectral range of sensitivity	$\lambda_{10\%}$	typ.	400 1100 nm
Radiant sensitive area	А	typ.	1.00 mm <sup>2</sup>
Dimensions of active chip area	L x W	typ.	1 x 1 mm x mm
Half angle	φ	typ.	10 °
Dark current V <sub>R</sub> = 20 V	I <sub>R</sub>	typ. max.	1 nA 5 nA
Spectral sensitivity of the chip $\lambda = 870 \text{ nm}$	$S_{\lambda}$	typ.	0.65 A / W
Quantum yield of the chip $\lambda = 870 \text{ nm}$	η	typ.	0.93 Electrons / Photon
Open-circuit voltage $E_v = 1000 \text{ lx}; \text{ Std. Light A}; V_R = 0 \text{ V}$	V <sub>o</sub>	min. typ.	350 mV 430 mV
Short-circuit current $E_v = 1000 \text{ lx}$ ; Std. Light A; $V_R = 0 \text{ V}$	I <sub>sc</sub>	typ.	125 µA
Rise time V <sub>R</sub> = 20 V; R <sub>L</sub> = 50 Ω; $\lambda$ = 850 nm	t <sub>r</sub>	typ.	0.005 µs
Fall time V <sub>R</sub> = 20 V; R <sub>L</sub> = 50 Ω; $\lambda$ = 850 nm	t <sub>r</sub>	typ.	0.005 µs
Forward voltage I <sub>F</sub> = 100 mA; E = 0	V <sub>F</sub>	typ.	1.3 V
Capacitance $V_R = 0 V$ ; f = 1 MHz; E = 0	C <sub>0</sub>	typ.	11 pF
Temperature coefficient of voltage	$TC_v$	typ.	-2.6 mV / K
Temperature coefficient of short-circuit current Std. Light A	TC	typ.	0.18 % / K
Noise equivalent power $V_R = 20 \text{ V}; \lambda = 870 \text{ nm}$	NEP	typ.	0.028 pW / Hz <sup>1/2</sup>
Detection limit $V_R = 20 \text{ V}; \lambda = 870 \text{ nm}$	D*	typ.	3.6e12 cm x Hz <sup>1/2</sup> / W



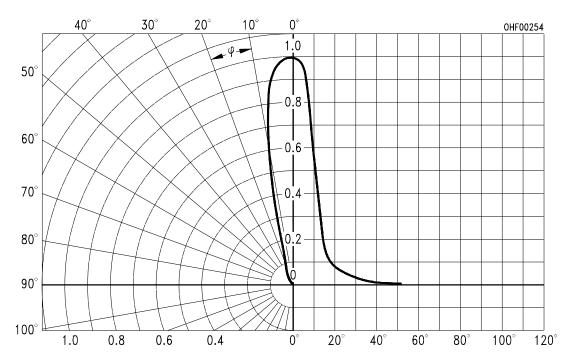
#### Relative Spectral Sensitivity <sup>2), 3)</sup>

 $S_{rel} = f(\lambda)$ 



#### Directional Characteristics <sup>2), 3)</sup>

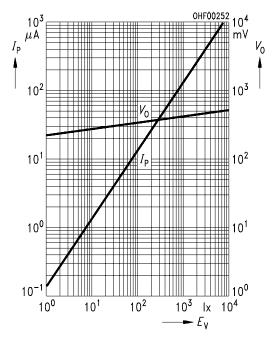
 $S_{rel} = f(\phi)$ 



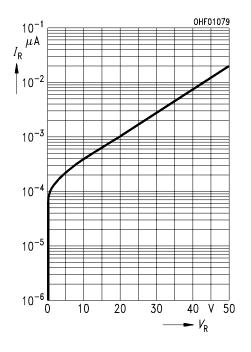


#### Photocurrent/Open-Circuit Voltage <sup>2), 3)</sup> Dark Current <sup>2), 3)</sup>

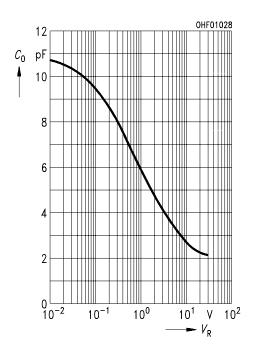
 $I_{_{
m P}}$  ( $V_{_{
m R}}$  = 5 V) /  $V_{_{
m O}}$  = f ( $E_{_{
m v}}$ )



 $I_R = f(V_R); E = 0$ 



Capacitance <sup>2), 3)</sup> C = f (V<sub>R</sub>); f = 1MHz; E = 0; T<sub>A</sub> = 25°C

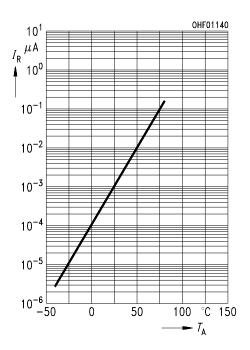






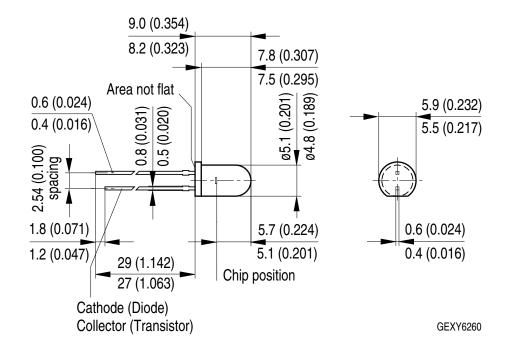
### Dark Current <sup>2)</sup>

 $I_{_{R}} = f(T_{_{A}}); E = 0; V_{_{R}} = 20 V$ 





#### **Dimensional Drawing**<sup>4)</sup>



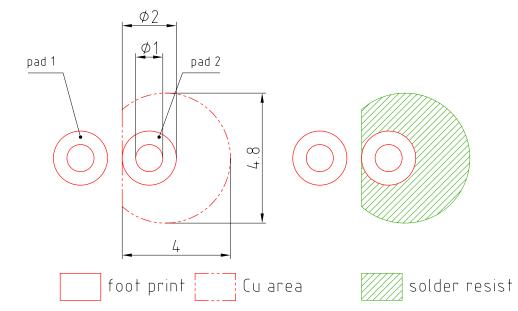
#### **Further Information:**

Approximate Weight:	350.0 mg
Package marking:	Cathode



E062.3010.188-01

#### Recommended Solder Pad<sup>4)</sup>



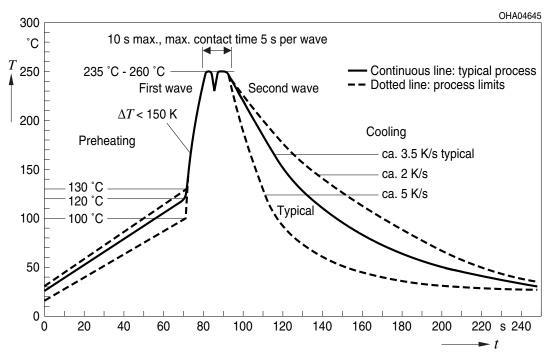
Pad 1: anode

#### SFH 213 DATASHEET



#### **TTW Soldering**

IEC-61760-1 TTW



#### Notes

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Packing information is available on the internet (online product catalog).

For further application related information please visit www.osram-os.com/appnotes



#### Disclaimer

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

#### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.



#### Glossary

- <sup>1)</sup> **Photocurrent:** The photocurrent values are measured (by irradiating the devices with a homogenous light source and applying a voltage to the device) with a tolerance of ±11 %.
- <sup>2)</sup> Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- <sup>3)</sup> **Testing temperature:** TA = 25°C (unless otherwise specified)
- <sup>4)</sup> **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



#### **Revision History**

Version	Date	Change
1.4	2022-08-11	Applications New Layout



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